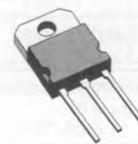


POWER DARLINGTONS

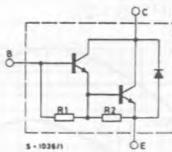
DESCRIPTION

The TIP140, TIP141, TIP142 are silicon epitaxial-base NPN transistors in monolithic Darlington configuration and are mounted in SOT-93 plastic package. They are intended for use in power linear and switching applications. The complementary PNP types are the TIP145, TIP146, TIP147 respectively.

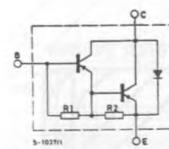


SOT-93

INTERNAL SCHEMATIC DIAGRAMS



R1 ≈ 5 kΩ
R2 ≈ 150 Ω



R1 ≈ 5 kΩ
R2 ≈ 150 Ω

ABSOLUTE MAXIMUM RATINGS

| Symbol | Parameter | NPN *PNP | Value | | | Unit |
|------------------|-------------------------------------------------------|-------------|------------------|------------------|------------------|------|
| | | | TIP140 TIP145 | TIP141 TIP146 | TIP142 TIP147 | |
| V _{CBO} | Collector-base Voltage ($I_E = 0$) | | 60 | 80 | 100 | V |
| V _{CEO} | Collector-emitter Voltage ($I_B = 0$) | | 60 | 80 | 100 | V |
| V _{EBO} | Emitter-base Voltage ($I_C = 0$) | | | 5 | | V |
| I _C | Collector Current | | | 10 | | A |
| I _{CM} | Collector Peak Current (repetitive) | | | 20 | | A |
| I _B | Base Current | | | 0.5 | | A |
| P _{tot} | Total Power Dissipation at $T_{case} \leq 25^\circ C$ | | | 125 | | W |
| T _{stg} | Storage Temperature | | | −65 to 150 | | °C |
| T _j | Junction Temperature | | | 150 | | °C |

* For PNP types voltage and current values are negative.

THERMAL DATA

| | | | | |
|-------------------------|----------------------------------|-----|---|------|
| $R_{th\ j\text{-case}}$ | Thermal Resistance Junction-case | Max | 1 | °C/W |
|-------------------------|----------------------------------|-----|---|------|

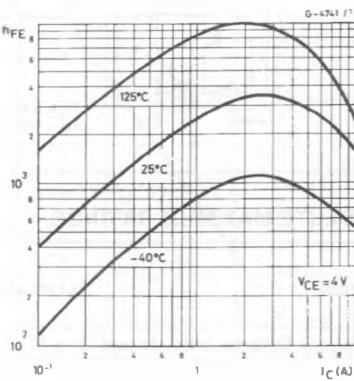
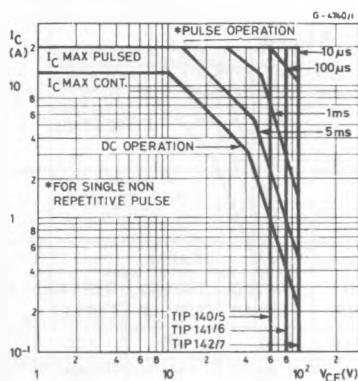
ELECTRICAL CHARACTERISTICS ($T_{case} = 25^\circ\text{C}$ unless otherwise specified)

| Symbol | Parameter | Test Conditions | | | Min. | Typ. | Max. | Unit |
|------------------|----------------------------------------------------|-------------------------------------------|------------------------------------------------|-----------------|------|------|------|---------------|
| I_{CBO} | Collector Cutoff Current ($I_E = 0$) | for TIP140/5 | $V_{CB} = 60\text{ V}$ | | | 1 | mA | |
| | | for TIP141/6 | $V_{CB} = 80\text{ V}$ | | | 1 | mA | |
| | | for TIP142/7 | $V_{CB} = 100\text{ V}$ | | | 1 | mA | |
| I_{CEO} | Collector Cutoff Current ($I_B = 0$) | for TIP140/5 | $V_{CB} = 30\text{ V}$ | | | 2 | mA | |
| | | for TIP141/6 | $V_{CE} = 40\text{ V}$ | | | 2 | mA | |
| | | for TIP142/7 | $V_{CE} = 50\text{ V}$ | | | 2 | mA | |
| I_{EBO} | Emitter Cutoff Current ($I_C = 0$) | $V_{EBO} = 5\text{ V}$ | | | | | 2 | mA |
| $V_{CEO(sus)}$ * | Collector-emitter Sustaining Voltage ($I_B = 0$) | $I_C = 30\text{ mA}$ | for TIP140/5 | 60 | | | | V |
| | | | for TIP141/6 | 80 | | | | V |
| | | | for TIP142/7 | 100 | | | | V |
| $V_{CE(sat)}$ * | Collector-emitter Saturation Voltage | $I_C = 5\text{ A}$ $I_C = 10\text{ A}$ | $I_B = 10\text{ mA}$ $I_B = 40\text{ mA}$ | | | 2 | V | |
| V_{BE} * | Base-emitter Voltage | $I_C = 10\text{ A}$ | $V_{CE} = 4\text{ V}$ | | | 3 | V | |
| h_{FE} * | DC current Gain | $I_C = 5\text{ A}$ $I_C = 10\text{ A}$ | $V_{CE} = 4\text{ V}$ $V_{CE} = 4\text{ V}$ | 1000 500 | | | | |
| t_{on} | Turn-on Time | $I_C = 10\text{ A}$ | $I_{B1} = 40\text{ mA}$ | | 0.9 | | | μs |
| t_{off} | Turn-off Time | $I_C = 10\text{ A}$ | $I_{B2} = -40\text{ mA}$ | $R_L = 3\Omega$ | 4 | | | μs |

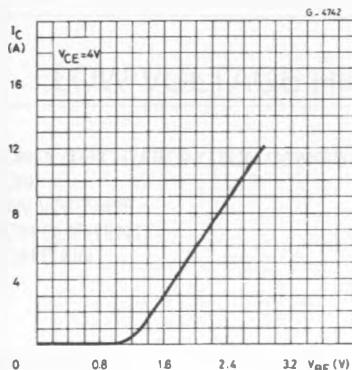
* Pulsed : pulse duration = 200 μs , duty cycle = 1.5%.
For PNP devices voltage and current values are negative.

Safe Operating Areas.

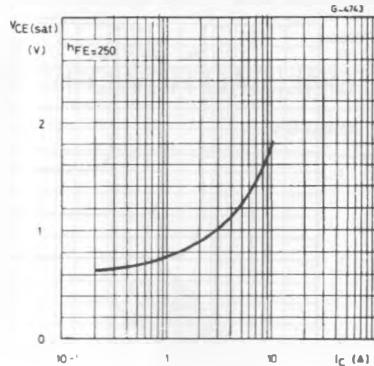
DC Current Gain (TIP140/1/2).



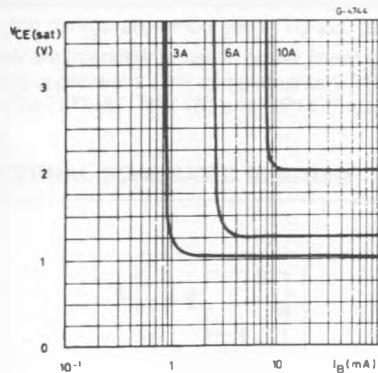
DC Transconductance (TIP140/1/2).



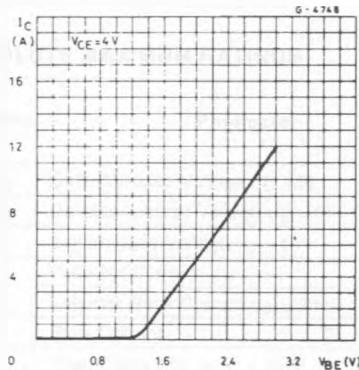
Collector-emitter Saturation Voltage (TIP140/1/2).



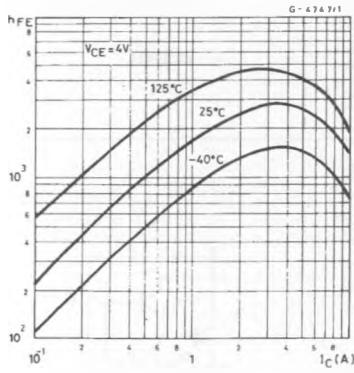
Collector-emitter Saturation Voltage (TIP140/1/2).



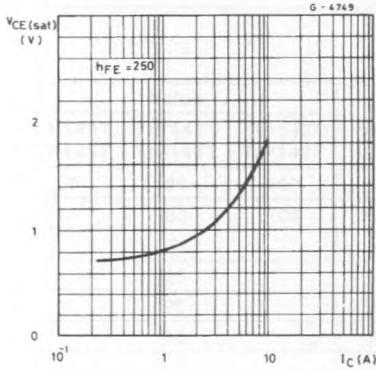
DC Transconductance (TIP145/6/7).



DC Current Gain (TIP145/6/7).



Collector-emitter Saturation Voltage (TIP145/6/7).



Collector-emitter Saturation Voltage (TIP145/6/7).

